

UNISONIC TECHNOLOGIES CO., LTD

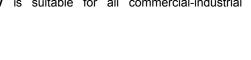
UFZ34V **Preliminary Power MOSFET**

28A, 60V **N-CHANNEL POWER MOSFET**

DESCRIPTION

The UTC UFZ34V is an N-channel Power MOSFET, it uses UTC's advanced technology to provide the customers with a minimum on state resistance, high switching speed and low gate charge.

The UTC UFZ34V is suitable for all commercial-industrial applications, etc.



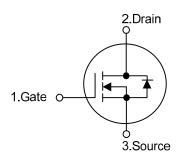


* High switching speed

FEATURES

* Low gate charge

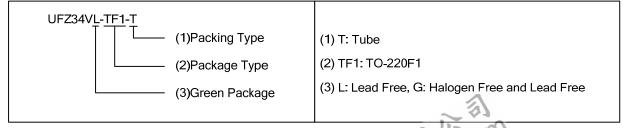




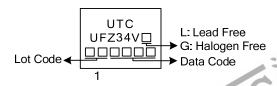
ORDERING INFORMATION

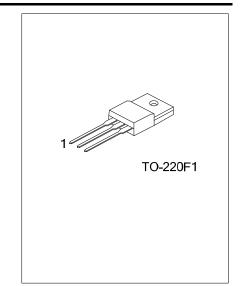
Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	- Package	1	2	3	Packing	
UFZ34VL-TF1-T	UFZ34VG-TF1-T	TO-220F1	G	D	S	Tube	

Pin Assignment: G: Gate D: Drain S: Source Note:



MARKING





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ABSOLUTE MAXIMUM RATINGS (T_C =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	60	V	
Gate-Source Voltage		V_{GSS}	±20	V	
Drain Current	Continuous	I _D	28	Α	
	Pulsed (Note 2)	I _{DM}	112	Α	
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	540	mJ	
Peak Diode Recovery dv/dt (Note 4)		dv/dt	20	V/ns	
Power Dissipation		P _D	55	W	
Junction Temperature		TJ	+150	°C	
Storage Temperature Range		T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature
- 3. L=120mH, I_{AS} =3.0A, V_{DD} = 50V, R_{G} =25 Ω , Starting T_{J} =25 $^{\circ}$ C
- 4. I_{SD} ≤28A, di/dt ≤200A/μs, V_{DD} ≤BV_{DSS}, Starting T_J=25°C

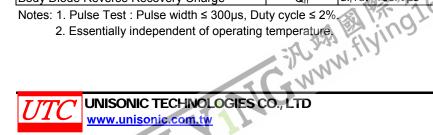
THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ_{JC}	2.27	°C/W	

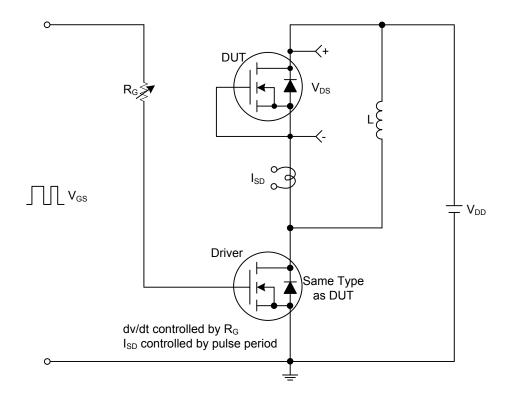
ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

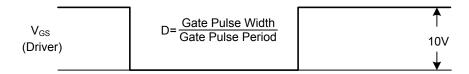
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I_D =250 μ A	60			V		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			25	μΑ		
Gate-Source Leakage Current	I_{GSS}	V_{DS} =0V , V_{GS} =±20V			±100	nA		
ON CHARACTERISTICS								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$			3.0	V		
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =14A			42	mΩ		
DYNAMIC PARAMETERS								
Input Capacitance	C _{ISS}			810		pF		
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, f=1.0MHz		260		pF		
Reverse Transfer Capacitance	C _{RSS}			18		pF		
SWITCHING PARAMETERS								
Total Gate Charge (Note 1)	Q_G	-V _{DD} =50V, V _{GS} =10V, I _D =1.3A , -I _G =100μA (Note 1, 2)		86		nC		
Gate to Source Charge	Q_GS			6		nC		
Gate to Drain Charge	Q_GD			5		nC		
Turn-ON Delay Time (Note 1)	$t_{D(ON)}$	\\ -20\\ \\ -40\\ -0.5A		36		ns		
Rise Time	t_R	V_{DD} =30V, V_{GS} =10V, I_{D} =0.5A, I_{G} =25 Ω , I_{D} =1.8 Ω		24		ns		
Turn-OFF Delay Time	t _{D(OFF)}	(Note 1, 2)		366		ns		
Fall-Time	t_{F}	(Note 1, 2)		64		ns		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Maximum Body-Diode Continuous Current	Is				28	Α		
Maximum Body-Diode Pulsed Current	I _{SM}	~ 3			112	Α		
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	I _S =28A, V _{GS} =0V	3		1.3	V		
Body Diode Reverse Recovery Time (Note 1)	t _{rr}	I _S =28A, V _{GS} =0V	*	50		ns		
Body Diode Reverse Recovery Charge	Q_{rr}	dl _F /dt=100A/μs		0.1		μC		

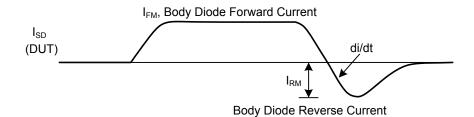
Notes: 1. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%

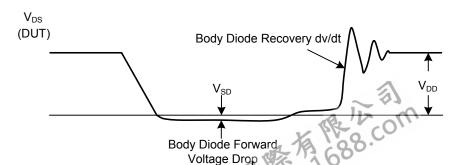


■ TEST CIRCUITS AND WAVEFORMS



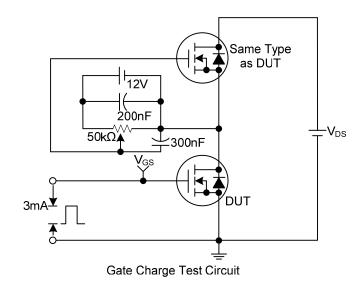


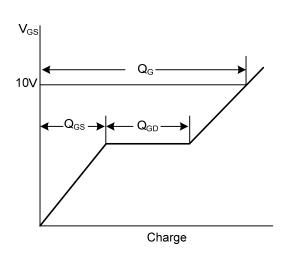




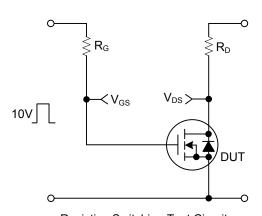
Peak Diode Recovery dv/dt Test Circuit and Waveforms

TEST CIRCUITS AND WAVEFORMS

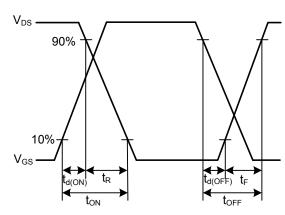




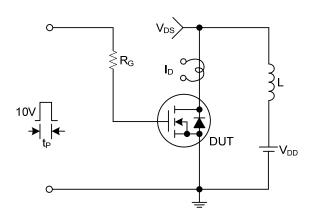
Gate Charge Waveforms



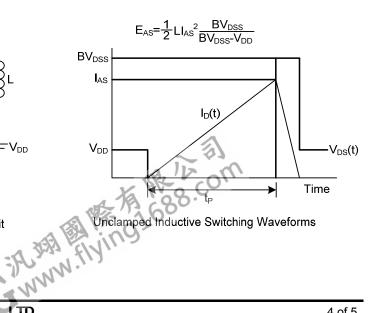




Resistive Switching Waveforms



Unclamped Inductive Switching Test Circuit



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